NSN 5961-01-098-4082

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-098-4082 **Inclosure Material:** Metal **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.104 inches and 0.140 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-15 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 reverse voltage, peak **Current Rating Per Characteristic:** 1.00 amperes source cutoff current and 35.00 amperes forward current, average universal **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No